

SOT223 N-CHANNEL ENHANCEMENT MODE LOW THRESHOLD VERTICAL DMOS FET

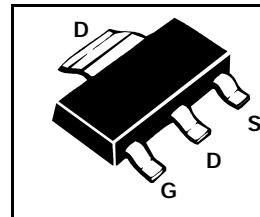
ISSUE 2 - JANUARY 1996

ZVNL120G

FEATURES

- * V_{DS} - 200V
- * $R_{DS(ON)}$ - 10Ω

PARTMARKING DETAIL - ZVNL120



ABSOLUTE MAXIMUM RATINGS.

PARAMETER	SYMBOL	VALUE	UNIT
Drain-Source Voltage	V_{DS}	200	V
Continuous Drain Current at $T_{amb}=25^{\circ}C$	I_D	320	mA
Pulsed Drain Current	I_{DM}	2	A
Gate-Source Voltage	V_{GS}	± 20	V
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{tot}	2	W
Operating and Storage Temperature Range	$T_j \cdot T_{stg}$	-55 to +150	°C

ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated).

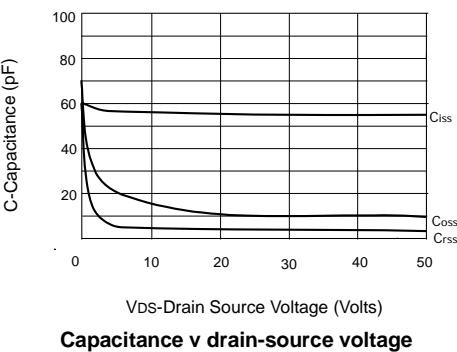
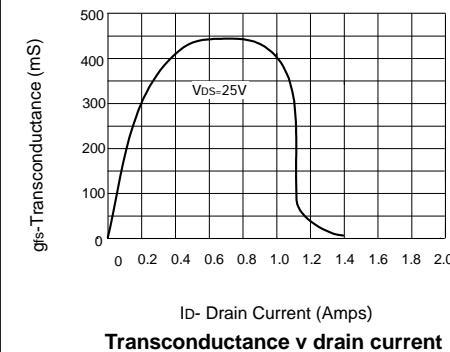
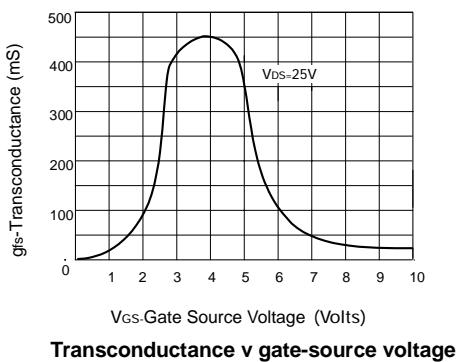
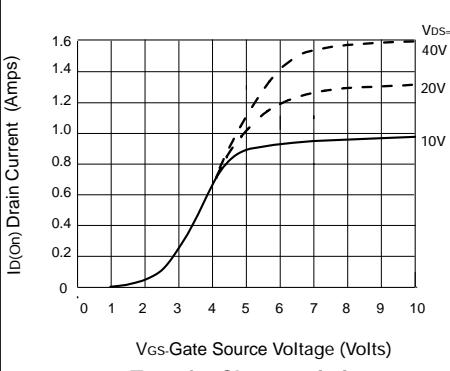
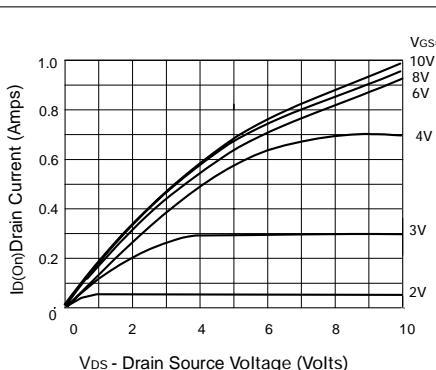
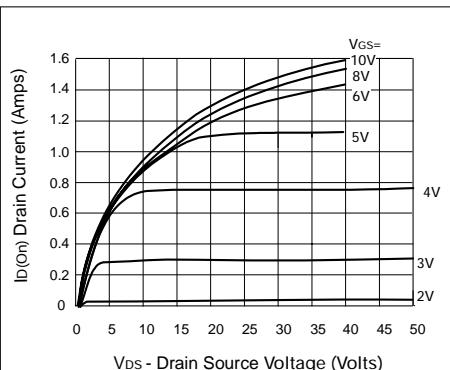
PARAMETER	SYMBOL	MIN.	MAX.	UNIT	CONDITIONS.
Drain-Source Breakdown Voltage	BV_{DSS}	200		V	$I_D=1\text{mA}$, $V_{GS}=0\text{V}$
Gate-Source Threshold Voltage	$V_{GS(th)}$	0.5	1.5	V	$I_D=1\text{mA}$, $V_{DS}=V_{GS}$
Gate-Body Leakage	I_{GSS}		100	nA	$V_{GS}=\pm 20\text{V}$, $V_{DS}=0\text{V}$
Zero Gate Voltage Drain Current	I_{DSS}		10 100	μA μA	$V_{DS}=200\text{V}$, $V_{GS}=0\text{V}$ $V_{DS}=160\text{V}$, $V_{GS}=0\text{V}$, $T=125^{\circ}\text{C}$ (2)
On-State Drain Current(1)	$I_{D(on)}$	500		mA	$V_{DS}=25\text{V}$, $V_{GS}=5\text{V}$
Static Drain-Source On-State Resistance (1)	$R_{DS(on)}$		10 10	Ω Ω	$V_{GS}=5\text{V}$, $I_D=250\text{mA}$ $V_{GS}=3\text{V}$, $I_D=125\text{mA}$
Forward Transconductance(1)(2)	g_{fs}	200		mS	$V_{DS}=25\text{V}$, $I_D=250\text{mA}$
Input Capacitance (2)	C_{iss}		85	pF	$V_{DS}=25\text{V}$, $V_{GS}=0\text{V}$, $f=1\text{MHz}$
Common Source Output Capacitance (2)	C_{oss}		20	pF	
Reverse Transfer Capacitance (2)	C_{rss}		7	pF	
Turn-On Delay Time (2)(3)	$t_{d(on)}$		8	ns	
Rise Time (2)(3)	t_r		8	ns	$V_{DD}=25\text{V}$, $I_D=250\text{mA}$
Turn-Off Delay Time (2)(3)	$t_{d(off)}$		20	ns	
Fall Time (2)(3)	t_f		12	ns	

(1) Measured under pulsed conditions. Width=300μs. Duty cycle ≤2%

(2) Sample test.

(3) Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator

TYPICAL CHARACTERISTICS



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TYPICAL CHARACTERISTICS

